# Fast Switching SPDT RF Switch

Absorptive RF Switch with internal driver Single Supply Voltage, +3V to +5V

## **Product Features**

- High Isolation, 52 dB at 1 GHz
- Low insertion loss, 0.8 dB typ. at 1 GHz
- Low supply current consumption, 50 μA typ.
- Fast Rise/Fall time, 16 ns typ.

# **Typical Applications**

- Defense
- Communication Infrastructure
- Test and Measurements



0.3 - 4500 MHz

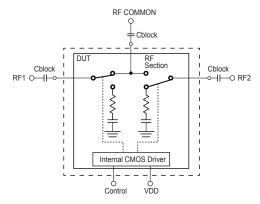
50Ω

#### CASE STYLE: DL805

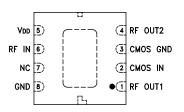
+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

### **General Description**

M3SWA-2-50DRA+ is a high isolation fast switching absorptive SPDT switch with integral CMOS driver, operates with single positive supply voltage while consuming, 50  $\mu$ A typical. It has been designed for wide-band operation. It is packaged in a tiny 3.25mm x 3.25mm, 8-lead package passes 250V for ESD (HBM).



### Simplified Schematic and Pad Description



Function	Pad Number	Description
RF IN	6	RF common/ SUM port, requires external DC block
RF OUT1	1	RF out #1/In port #1, requires external DC block
RF OUT2	4	RF out #1/In port #2, requires external DC block
CONTROL	2	CMOS Control IN
VDD	5	Supply voltage
NC	7	No Connection
CMOS GND	3	CMOS ground
GND	8 &, paddle	RF ground

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## **SPDT RF Switch**

# M3SWA-2-50DRA+

Parameter	Condition (MHz)	Min.	Тур.	Max.	Units
Frequency range		10		4500	MHz
	10		0.6	1.0	
	100		0.7	1.0	
Insertion loss <sup>2,3</sup>	1000		0.8	1.2	dB
	2000		1.0	1.4	
	4500		1.2	1.9	
	10		74.0		
	100		59.3		
Isolation between Common port and RF1/RF2 Ports	1000		61.5		dB
	2000		50.8		
	4500		39.5		
	10		74.3		
	100		61.0		
Isolation between RF1 and RF2 ports	1000		51.8		dB
	2000		46.5		
	4500		37.4		
	10		24.3		
	100		24.1		
Return loss (ON STATE)	1000		20.8		dB
	2000		16.7		
	4500		17.0		
	500		12.9		
	1000		20.1		
Return loss (OFF STATE)	2000		28.6		dB
	4500		12.8		
	500-1000		30		
Input 0.2 dB Compression	1000-2000		30		dBm
	2000-4500		27		

#### **RF Electrical Specifications**<sup>1</sup>, $T_{\text{sup}}=25^{\circ}\text{C}$ , $50\Omega$ , $V_{\text{pp}}=+5V$

### **DC Electrical Specifications**

Parameter	Min.	Тур.	Max.	Units
Supply voltage, V <sub>DD</sub>	3.0		5.0	V
Supply current		50	200	μA
Control voltage Low	0		0.5	V
Control voltage High	0.7 V <sub>DD</sub>		V <sub>DD</sub>	V
Control current		0.2	10	μA

Notes:

1. Tested on Mini-Circuits' test board TB-159+, using Agilent's N5230A network analyzer (see Characterization test circuit, Fig.1). 2. Insertion loss values are de-embedded from test board loss.

3. Needs external blocking capacitors on all RF ports. (Suggested value=47pF)

#### **Switching Specifications**

Parameter	Condition	Min.	Тур.	Max.	Units
Switching time 50% Control to 90%/10% RF	RF Pin=0dBm RF Freq.=500 MHz Control Freq.=500 KHz Control High=3.7V Control Low=0V		29		nS
Video Leakage	RF Pin=0dBm RF Freq.=500 MHz Control Freq.=500 KHz Control High=3.7V Control Low=0V		24.8		mV
Rise/Fall Time 10 to 90% or 90 to 10%	RF Pin=0dBm RF Freq.=500 MHz Control Freq.=500 KHz Control High=3.7V Control Low=0V		16		nS

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#### Absolute Maximum Ratings<sup>5</sup>

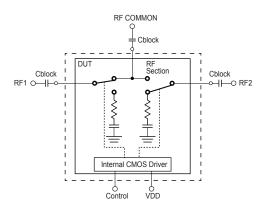
Parameter	Ratings	
Operating temperature	-55°C to +100°C	
Storage temperature	-55°C to +100°C	
V <sub>DD</sub> , Supply voltage (V)	2.7 Min., 5.5 Max.	
Voltage control (V)	-0.2V Min., V <sub>DD</sub> Max	
RF Input power (dBm)	+30 dBm	

5. Operation of this device above any of these conditions may cause permanent damage.

#### Truth Table (State of control voltage selects the desired switch state)

State of Control voltage	RF common to		
State of Control Voltage	RF1	RF2	
Hi	OFF	ON	
Low	ON	OFF	

ON- low insertion loss state OFF- Isolation State

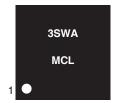


# **Characterization Test Circuit**

Figure 1. Block Diagram of test Circuit used for characterization (DUT soldered on Mini-Circuit's TB-159A+)

Frequency (MHz)	Cblock (Suggested Value)
0.3-500	0.1 µF
500-4500	47 pF

# **Product Marking**



Marking may contain other features or characters for internal lot control

## Additional Detailed Technical Information

additional information is available on our dash board.

Performance Data	Data Table		
	Swept Graphs		
Case Style	DL805 Plastic package, exposed paddle , lead finish=Matte-Tin		
Tape & Reel	F58		
Standard quantities available on reel	7" reels with 1000 devices 13" reels with 2000, 4000 devices		
Suggested Layout for PCB Design	PL-120A		
Evaluation Board	TB-159A+		
Environmental Ratings	ENV16		

### **ESD** Rating

Human Body Model (HBM): Class 1A (250 to 500V) in accordance with ESD STM5.1-2001

**Additional Notes** 

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
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